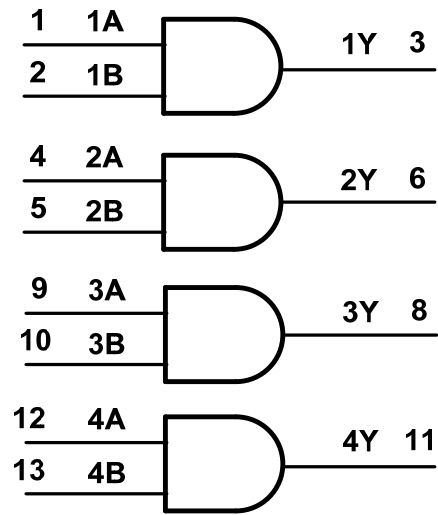


## Pin Descriptions

Pin Number	Pin Name	Description
1	1A	Data Input
2	1B	Data Input
3	1Y	Data Output
4	2A	Data Input
5	2B	Data Input
6	2Y	Data Output
7	GND	Ground
8	3Y	Data Output
9	3A	Data Input
10	3B	Data Input
11	4Y	Data Output
12	4A	Data Input
13	4B	Data Input
14	Vcc	Supply Voltage

## Logic Diagram



## Function Table

Inputs		Output
A	B	Y
L	X	L
X	L	L
H	H	H

## Absolute Maximum Ratings (Note 5) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Description	Rating	Unit
ESD HBM	Human Body Model ESD Protection	2	kV
ESD CDM	Charged Device Model ESD Protection	1	kV
ESD MM	Machine Model ESD Protection	200	V
V <sub>CC</sub>	Supply Voltage Range	-0.5 to +7.0	V
V <sub>I</sub>	Input Voltage Range	-0.5 to +7.0	V
I <sub>IK</sub>	Input Clamp Current V <sub>I</sub> < 0V	-20	mA
I <sub>OK</sub>	Output Clamp Current V <sub>O</sub> < -0V	-50	mA
I <sub>O</sub>	Continuous Output Current -0.5V < V <sub>O</sub> < V <sub>CC</sub> + 0.5V	±25	mA
I <sub>CC</sub>	Continuous Current Through V <sub>CC</sub>	50	mA
I <sub>GND</sub>	Continuous Current Through GND	-50	mA
T <sub>J</sub>	Operating Junction Temperature	-40 to +150	°C
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C
P <sub>TOT</sub>	Total Power Dissipation	500	mW

Note: 5. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

**Recommended Operating Conditions** (Note 6) (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>CC</sub>	Supply Voltage	—	2.0	5.5	V
V <sub>I</sub>	Input Voltage	—	0	5.5	V
V <sub>O</sub>	Output Voltage	—	0	V <sub>CC</sub>	V
I <sub>OH</sub>	High-Level Output Current	2.0V	—	-50	mA
		2.3V to 2.7V	—	-2	μA
		3.0V to 3.6V	—	-6	mA
		4.5V to 5.5V	—	-12	mA
I <sub>OL</sub>	Low-Level Output Current	2.0V	—	50	μA
		2.3V to 2.7V	—	2	mA
		3.0V to 3.6V	—	6	mA
		4.5V to 5.5V	—	12	mA
Δt/ΔV	Input Transition Rise or Fall Rate	2.3V to 2.7V	—	200	ns/V
		3.0V to 3.6V	—	100	
		4.5V to 5.5V	—	20	
T <sub>A</sub>	Operating Free-Air Temperature	—	-40	+125	°C

Note: 6. Unused inputs should be held at V<sub>CC</sub> or Ground.

**Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Symbol	Parameter	Test Conditions	V <sub>CC</sub>	T <sub>A</sub> = -40 to +85°C		T <sub>A</sub> = -40 to +125°C		Unit
				Min	Max	Min	Max	
V <sub>IH</sub>	High-Level Input Voltage	—	2.0V	1.5	—	1.5	—	V
		—	2.3V to 2.7V	V <sub>CC</sub> X 0.7	—	V <sub>CC</sub> X 0.7	—	
		—	3.0V to 3.6V	V <sub>CC</sub> X 0.7	—	V <sub>CC</sub> X 0.7	—	
		—	4.5V to 5.5V	V <sub>CC</sub> X 0.7	—	V <sub>CC</sub> X 0.7	—	
V <sub>IL</sub>	Low-Level Input Voltage	—	2.0V	—	0.5	—	0.5	V
		—	2.3V to 2.7V	—	V <sub>CC</sub> X 0.3	—	V <sub>CC</sub> X 0.3	
		—	3.0V to 3.6V	—	V <sub>CC</sub> X 0.3	—	V <sub>CC</sub> X 0.3	
		—	4.5V to 5.5V	—	V <sub>CC</sub> X 0.3	—	V <sub>CC</sub> X 0.3	
V <sub>OH</sub>	High-Level Output Voltage	I <sub>OH</sub> = -50μA	2.0V to 5.5V	V <sub>CC</sub> -0.1	—	V <sub>CC</sub> -0.1	—	V
		I <sub>OH</sub> = -2mA	2.3V	2.0	—	2.0	—	
		I <sub>OH</sub> = -6mA	3.0V	2.48	—	2.48	—	
		I <sub>OH</sub> = -12mA	4.5V	3.8	—	3.8	—	
V <sub>OL</sub>	Low-Level Output Voltage	I <sub>OL</sub> = 50μA	2.0V to 5.5V	—	0.1	—	0.1	V
		I <sub>OL</sub> = 2mA	2.3V	—	0.4	—	0.4	
		I <sub>OL</sub> = 6mA	3.0V	—	0.44	—	0.44	
		I <sub>OL</sub> = 12mA	4.5V	—	0.55	—	0.55	
I <sub>OFF</sub>	Power Down Leakage Current	V <sub>I</sub> or V <sub>O</sub> = 0 to 5.5V	0V	—	5	—	5	μA
I <sub>I</sub>	Input Current	V <sub>I</sub> = GND or 5.5V	0 to 5.5V	—	±1	—	±1	μA
I <sub>CC</sub>	Supply Current	V <sub>I</sub> = GND or V <sub>CC</sub> I <sub>O</sub> = 0	5.5V	—	20	—	20	μA

## Switching Characteristics

Symbol	Parameter	Test Conditions	V <sub>CC</sub>	T <sub>A</sub> = +25°C			-40°C to +85°C		-40°C to +125°C		Unit
				Min	Typ	Max	Min	Max	Min	Max	
t <sub>PD</sub>	Propagation Delay A <sub>N</sub> to Y <sub>N</sub>	Figure 1 C <sub>L</sub> = 15pF	2.5V ± 0.2V	—	7.9	13.8	1	16	1	17	ns
			3.3V ± 0.3V	—	5.6	8.8	1	10.5	1	11.5	
			5.0V ± 0.5V	—	4.1	5.9	1	7	1	8	
		Figure 1 C <sub>L</sub> = 50 pF	2.5V ± 0.2V	—	10.5	17.3	1	20	1	21	ns
			3.3V ± 0.3V	—	7.5	12.5	1	14	1	15	
			5.0V ± 0.5V	—	5.5	7.9	1	9	1	10	

## Operating Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Parameter		Test Conditions	V <sub>CC</sub>	Typ	Unit
C <sub>pd</sub>	Power Dissipation Capacitance per Gate	F= 10 MHz C <sub>L</sub> =50pF	3.3V	8	pF
			5.0V	10	

## Noise Characteristics

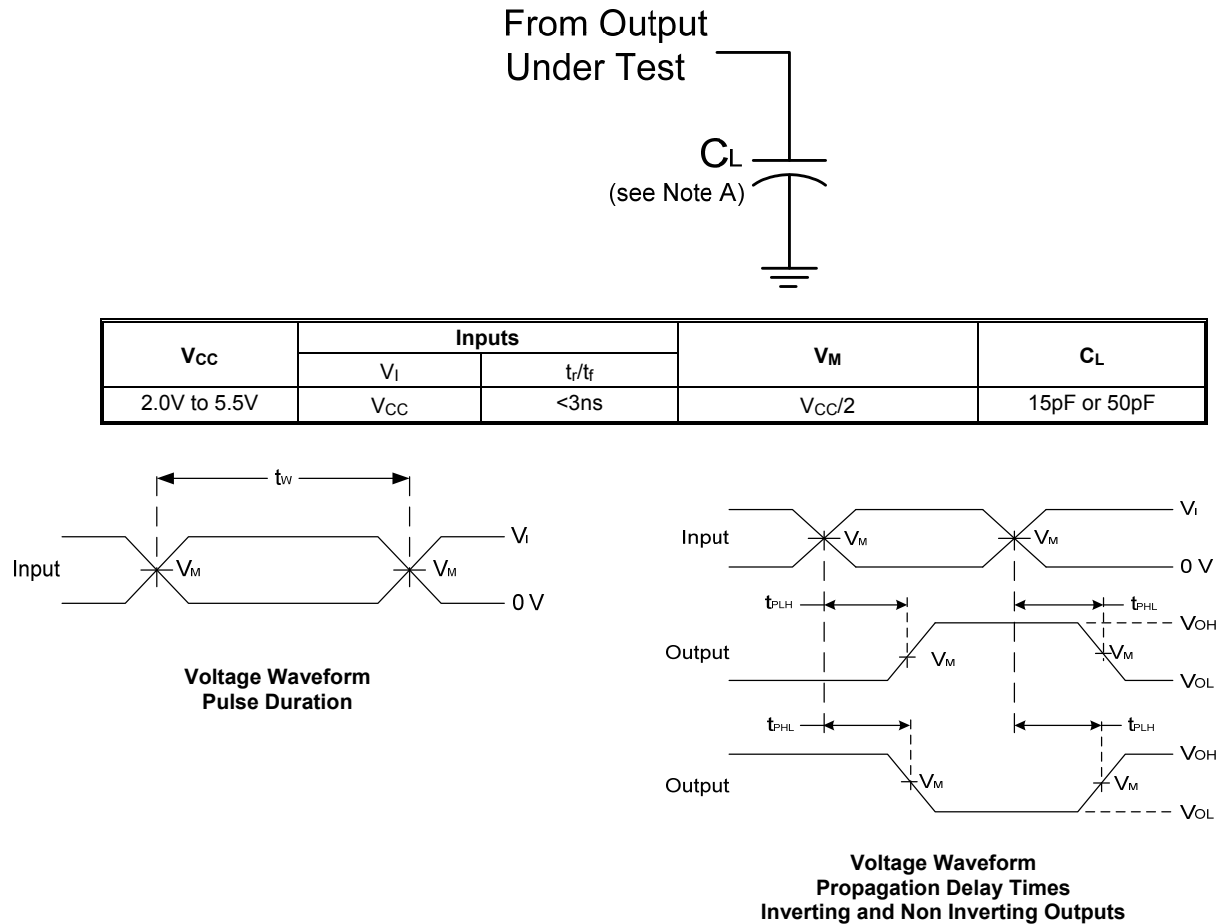
V<sub>CC</sub> = 3V, C<sub>L</sub> = 50pF T<sub>A</sub> = +25°C

Symbol	Parameter	Min	Typ	Max	Unit
V <sub>OL(p)</sub>	Quiet Output, Maximum Dynamic V <sub>OL</sub>	—	0.2	0.8	V
V <sub>OL(V)</sub>	Quiet Output, Minimum Dynamic V <sub>OL</sub>	—	-0.1	-0.8	V
V <sub>OH(V)</sub>	Quiet Output, Minimum Dynamic V <sub>OH</sub>	—	3.1	—	V
V <sub>IH(D)</sub>	High Level Dynamic Input Voltage	2.31	—	—	V
V <sub>IL(D)</sub>	Low Level Dynamic Input Voltage	—	—	0.99	V

## Package Characterisitics

Symbol	Parameter	Test Conditions	V <sub>CC</sub>	Min	Typ	Max	Unit
C <sub>i</sub>	Input Capacitance	V <sub>i</sub> = V <sub>CC</sub> – or GND	2.0V to 5.5V	—	3.3	10	pF

## Parameter Measurement Information

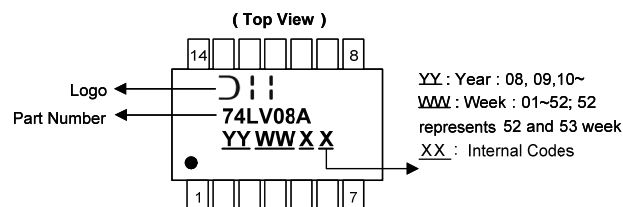


- Notes:
- A. Includes test lead and test apparatus capacitance.
  - B. All pulses are supplied at pulse repetition rate  $\leq 10\text{MHz}$
  - C. Inputs are measured separately one transition per measurement
  - D.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{PD}$

**Figure 1 Load Circuit and Voltage Waveforms**

## Marking Information

(1) SO14, TSSOP14



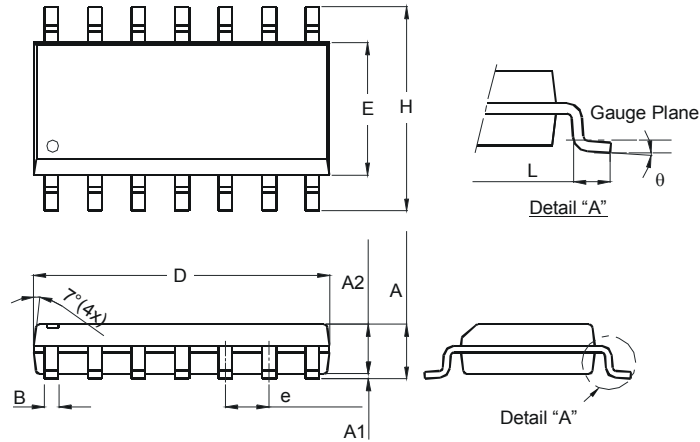
Part Number	Package
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74LV08AS14	SO-14
74LV08AT14	TSSOP-14

## Package Outline Dimensions (All dimensions in mm.)

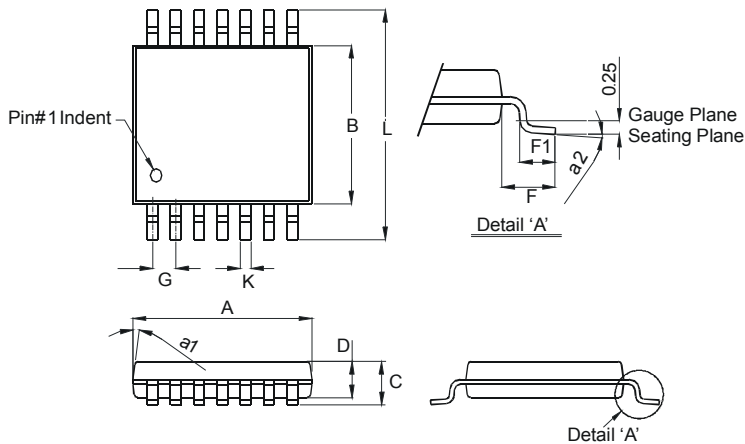
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.

### Package Type: SO-14



SO-14		
Dim	Min	Max
A	1.47	1.73
A1	0.10	0.25
A2	1.45 Typ	
B	0.33	0.51
D	8.53	8.74
E	3.80	3.99
e	1.27 Typ	
H	5.80	6.20
L	0.38	1.27
θ	0°	8°
All Dimensions in mm		

### Package Type: TSSOP-14

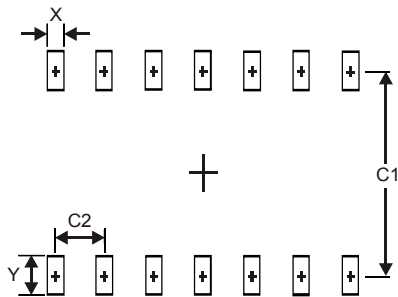


TSSOP-14		
Dim	Min	Max
a1	7° (4X)	
a2	0°	8°
A	4.9	5.10
B	4.30	4.50
C	—	1.2
D	0.8	1.05
F	1.00 Typ	
F1	0.45	0.75
G	0.65 Typ	
K	0.19	0.30
L	6.40 Typ	
All Dimensions in mm		

## Suggested Pad Layout

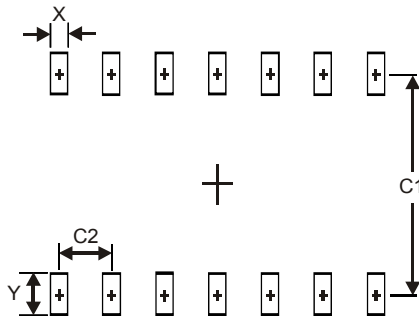
Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.

### Package Type: SO-14



Dimensions	Value (in mm)
X	0.60
Y	1.50
C1	5.4
C2	1.27

### Package Type: TSSOP-14



Dimensions	Value (in mm)
X	0.45
Y	1.45
C1	5.9
C2	0.65

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